

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: IWASAKI et al.
Serial No.: (New Continuation Application under 37 CFR §1.53(b) of
U.S. Application Serial No. 09/787,528)
Filed: July 3, 2003
For: SEMICONDUCTOR DEVICE
Group: 2813
Examiner: S. Smoot

PRELIMINARY AMENDMENT

MS: PATENT APPLICATIONS

Commissioner For Patents
Post Office Box 1450
Alexandria, VA 22313-1450

July 3, 2003

Sir:

Prior to examination, please amend the above-identified application as follows:

In the Title:

PLEASE AMEND THE TITLE TO READ AS FOLLOWS:

**SEMICONDUCTOR DEVICE WITH MULTILAYER CONDUCTIVE
STRUCTURE FORMED ON A SEMICONDUCTOR SUBSTRATE.**